

**DESCRIPTION**

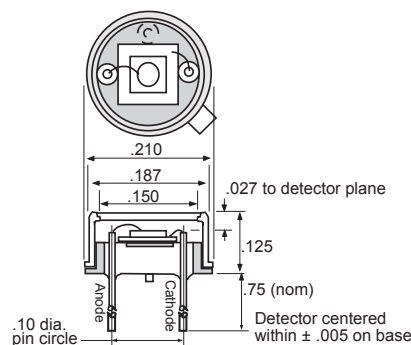
The J16A series Germanium Avalanche Photodiodes (APDs) are designed for high-speed applications at 800 and 1300 nm. Teledyne Judson APDs offer low dark currents and bandwidths up to 1.5GHz with active sizes of 100µm and 300µm diameter.

The J16A series APDs have undergone extensive reliability testing. Reliability has been demonstrated to be better than 10 FITs corresponding to less than 1% failure rate over 20 years service. Reliability data available upon request.

**APPLICATIONS**

- Local Area Networks
- OTDRs
- Transmission Systems

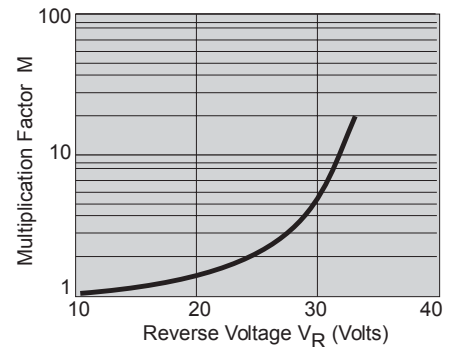
Figure 1  
 J16A-18A Package



**MULTIPLICATION CHARACTERISTICS**

An internal gain mechanism makes the J16A the solid state counterpart of the photomultiplier tube. This internal gain is known as the Multiplication Factor (M) and is a function of the reverse bias voltage  $V_R$  applied to the diode (Fig. 2).

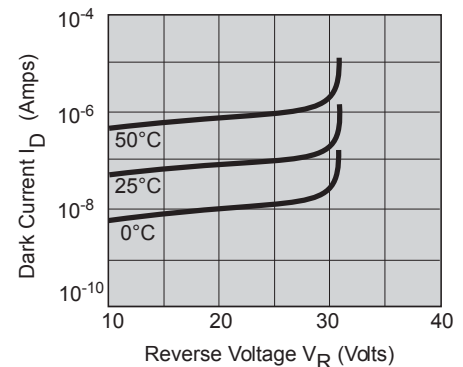
Figure 2  
 Multiplication Characteristics



**BREAKDOWN VOLTAGE AND DARK CURRENT**

The avalanche breakdown voltage  $V_B$  is the reverse bias voltage at which the diode's dark current becomes infinite. In practice, the dark current used to define breakdown voltage is 100µA (Fig. 3).

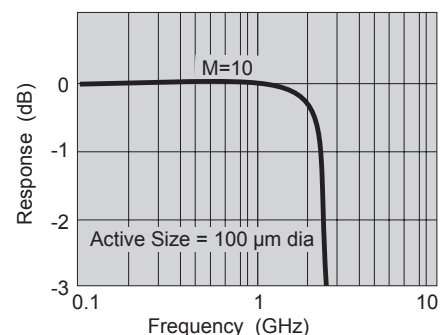
Figure 3  
 Dark Current and Reverse Voltage



**CUTOFF FREQUENCY**

The cutoff frequency  $f_c$  is the frequency at which the output signal power is down by 3dB. In the high multiplication region, the product of M and bandwidth becomes a constant called the gain-bandwidth product and cutoff frequency decreases with increasing M (Fig. 4).

Figure 4  
 Frequency Response



**J16A SERIES**  
**GERMANIUM AVALANCHE PHOTODIODES**  
 Operating Instructions



**TELEDYNE**  
**JUDSON TECHNOLOGIES**  
 A Teledyne Technologies Company

Parameter	Test Conditions	J16A-18A-R100U Active Size 100µm dia.			J16A-18A-R300U Active Size 300µm dia.			Units
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Quantum Efficiency	= 1300nm	60	70	--	60	70	--	%
Responsivity R	M = 1	0.63	0.73	--	0.63	0.73	--	A/W
Breakdown Voltage V <sub>B</sub>	I <sub>D</sub> = 100µA	20	25	40	20	25	40	V
Temp Coefficient of V <sub>B</sub>		0.1	--	--	0.1	--		%/°C
Dark Current I <sub>D</sub>	V <sub>R</sub> = 0.9 V <sub>B</sub>	--	0.3	0.5	--	1.4	3	µA
Multiplied Dark Current I <sub>DM</sub>	M = 1	--	100	150	--	300	400	nA
Cutoff Frequency (-3dB) f <sub>c</sub>	= 1300nm, M = 10, RL = 50	1000	1500	--	300	500	--	MHz
Excess Noise Factor F	= 300nm, f = 30MHz	--	9	--	--	9	--	--
Excess Noise Figure x	BW = 1MHz, M = 10, I <sub>ph</sub> = 2µA	--	0.95	--	--	0.95	--	--
Capacitance C	f = 1MHz, M = 10	--	1.5	2	--	8	10	pF
Forward Current I <sub>f</sub>	Maximum Rating			100			100	mA
Reverse Current I <sub>R</sub>	Maximum Rating			1			3	mA

Information in this document is believed to be reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.